

3. Anode o

• Wave Soldering or per MIL-STD-750 Method 2026.

Absolute Maximum Ratings^{*} $T_a = 25^{\circ}C$ unless otherwise noted

| Symbol | Parameter | Value | Unit | |
|--------------------|--|---------------------------------|------|--|
| V _{RRM} | Maximum Repetitive Reverse Voltage | 200 | V | |
| V _R | Maximum DC Reverse Voltage | 200 | V | |
| I _{F(AV)} | Average Rectified Forward Current, T _C =115°C | 10 (Per Leg) 20 (Per Device) | А | |
| I _{FSM} | Peak Forward Surge Current, 8.3mS Half Sine wave | 150 | А | |
| T _{STG} | Storage Temperature Range | -55 to +150 | °C | |
| Т _Ј | Operating Junction Temperature | 150 | °C | |

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics* T_a = 25°C unless otherwise noted

| Symbol | Parameter | Max. | Unit | |
|-------------------------------------|---|------|------|--|
| $R_{	extsf{	heta}JC}$ | Thermal Resistance, Junction to Case per Leg | 1.5 | °C/W | |
| $R_{	hetaJA}$ | Thermal Resistance, Junction to Ambient per Leg | 62.5 | °C/W | |
| * MIL standard 992 1012 8 JESDE1 10 | | | | |

* MIL standard 883-1012 & JESD51-10

Electrical Characteristics^{*} $T_a = 25^{\circ}C$ unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Max. | Unit |
|----------------|-----------------|--|------|--------------------------|------|
| ۱ _R | Reverse Current | $V_R=200V$ $T_C = 25 °C$ $V_R=200V$ $T_C = 125 °C$ | | 0.2 5 | mA |
| V _F | Forward Voltage | $ \begin{array}{ll} I_{F}{=}10A & T_{C}{=}25\ ^{\circ}C \\ I_{F}{=}10A & T_{C}{=}125\ ^{\circ}C \\ I_{F}{=}20A & T_{C}{=}25\ ^{\circ}C \\ I_{F}{=}20A & T_{C}{=}125\ ^{\circ}C \end{array} $ | | 0.9 0.8 1.0 0.9 | V |

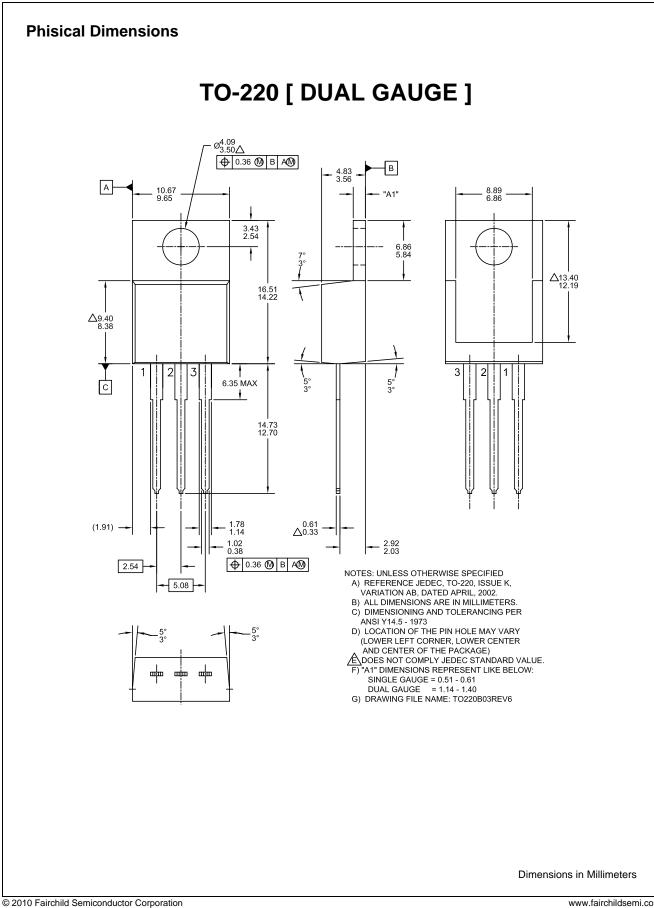
* DC Item are tested by Pulse Test : Pulse Width≤300µs, Duty Cycle≤2%

2. and Tab Cathode

MBR20200CT — Dual High Voltage Schottky Rectifier

Typical Performance Characteristics Figure 1. Forward Current Characteristics Figure 2. Reverse Leakage Current 1000 10 100 Forward Current, I_F[A] Reverse Current, I_R[uA] T_=125 °C 10 1 T =75 °C 75 °C 0.1 0.1 =25 °C 0.01 T_=25 ℃ 0.01 1E-3 0.0 0.1 0.2 0.3 0.5 0.6 0.7 0.8 0.9 1.0 0.4 50 100 150 200 Forward Voltage Drop, V_F[V] Reverse Voltage, V_R[V] **Figure 3.Junction Capacitance** Figure 4. Power Derating 30 1 0.9 0.8 0.7 0.6 Average Forward Current, I FIAN 1mhz 25 Juntion Capacitance, C_[[nF] DC 0.5 20 0.4 15 0.3 10 0.2 5 0 L 0 0.1 L 0 150 25 50 75 100 125 2 4 6 8 10 Case Temperature, $T_c[^{\circ}C]$ Reverse Voltage, V_R[V] © 2010 Fairchild Semiconductor Corporation

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